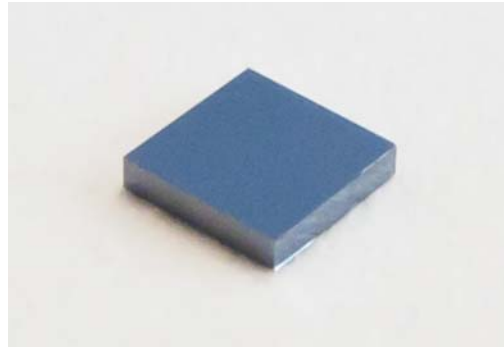


B-M-1030nm-2x2**Bragg mirror 1030 nm with chip area 2.0 mm x 2.0 mm on GaAs**

Material:	AlAs/GaAs epitaxial Bragg mirror on single crystalline GaAs substrate
Chip area	2.0 mm x 2.0 mm; other dimensions on request
Chip thickness	450 μm

Spectral reflectance